

General Description

The Sanrise SRC65R170B is a high voltage power MOSFET, fabricated using advanced super junction technology. The resulting device has extremely low on resistance, low gate charge and fast switching time, making it especially suitable for applications which require superior power density and outstanding efficiency.

The SRC65R170B break down voltage is 650V and it has a high rugged avalanche characteristics. The SRC65R170B is available in TO-247, TO-263-2, TO-220C and TO-220F packages.

Features

- Ultra Low $R_{DS(ON)} = 170m\Omega @ V_{GS} = 10V$.
- $V_{ds@T_{jmax}} = 700V$.
- Ultra Low Gate Charge, $Q_g = 47.8nC$ typ.
- Fast switching capability
- Robust design with better EAS performance
- Non-automotive Qualified
- Ultra-fast body diode

Application

- AC/DC Power Supply
- PC Power
- Server / Telecom
- Solar Inverter

Ordering Information

Circuit Type		SRC65R170B□□-□	
Package		E: Lead Free G: Green Blank: Tube TR: Tape & Reel	
T: TO-247			
TF: TO-220F			
S2: TO-263-2			
TC: TO-220C			

Symbol

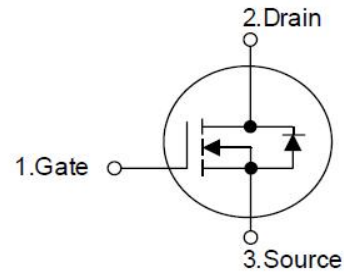


Figure 1 Symbol of SRC65R170B

Package Type

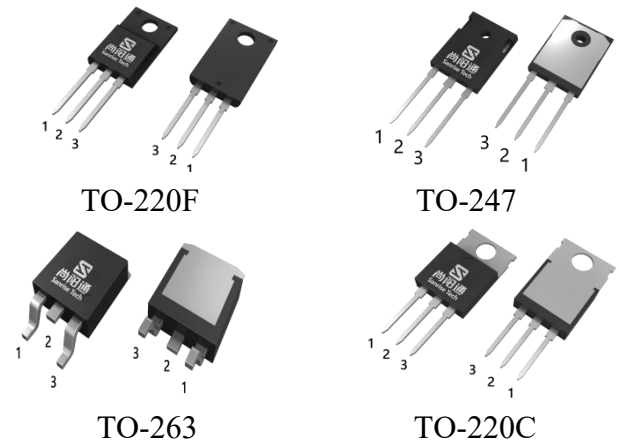


Figure 2 Package Types of SRC65R170B

Package	Part Number	Marking ID	Packing Type
TO-247	SRC65R170BT-G	SRC65R170BTG	Tube
TO-220F	SRC65R170BTF-G	SRC65R170BTFG	Tube
TO-220C	SRC65R170BTC-G	SRC65R170BTCG	Tube
TO-263-2	SRC65R170BS2TR-G	SRC65R170BS2G	Tape & Reel

Absolute Maximum Ratings

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	650	V
Gate-Source Voltage (static)		V_{GSS}	±20	V
Gate-Source Voltage (dynamic), AC ($f > 1$ Hz)		V_{GSS}	±30	V
Power Dissipation(TO-220C,TO-263-2,TO-247, $T_c=25^{\circ}\text{C}$)		P_{tot}	160.2	W
Power Dissipation(TO-220F, $T_c=25^{\circ}\text{C}$)		P_{tot}	33	W
Continuous Drain Current	$T_c=25^{\circ}\text{C}$	I_D	20.4	A
	$T_c=100^{\circ}\text{C}$		12.8	
	$T_c=125^{\circ}\text{C}$		9.1	
Pulsed Drain Current (Note 2)		I_{DM}	81.6	A
Avalanche Energy, Single Pulse (Note 3)		E_{AS}	86	mJ
Avalanche Energy, Single Pulse (Note 4)		E_{AS}	877	mJ
Avalanche Energy, Repetitive (Note 2)		E_{AR}	0.1	mJ
Avalanche Current, Repetitive (Note 2)		I_{AR}	1.6	A
Continuous Diode Forward Current		I_S	20.4	A
Diode Pulse Current		$I_{S,PULSE}$	81.6	A
MOSFET dv/dt Ruggedness, $V_{DS} \leq 480\text{V}$		dv/dt	80	V/ns
Reverse Diode dv/dt , $V_{DS} \leq 480\text{V}$, $I_{SD} \leq I_D$		dv/dt	50	V/ns
Operating Junction Temperature		T_J	150	$^{\circ}\text{C}$
Storage Temperature		T_{STG}	-55 to 150	$^{\circ}\text{C}$
Lead Temperature (Soldering, 10 sec)		T_{LEAD}	260	$^{\circ}\text{C}$

Note:

1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
2. Repetitive Rating: Pulse width limited by maximum junction temperature
3. $I_{AS}=1.6\text{A}$, $V_{DD}=60\text{V}$, $R_G=25\Omega$, Starting $T_J=25^{\circ}\text{C}$. Finish goods test condition.
4. $I_{AS}=5.1\text{A}$, $V_{DD}=60\text{V}$, $R_G=25\Omega$, Starting $T_J=25^{\circ}\text{C}$. Typical Eas.

Thermal characteristics

Parameter		Symbol	Min	Typ	Max	Unit
Thermal resistance, Junction-to-Case	TO-220F	R_{thJC}			3.7	$^{\circ}\text{C}/\text{W}$
	TO-220C				0.78	
	TO-263-2				0.78	
	TO-247				0.78	
Thermal resistance, Junction-to-Ambient	TO-220F	R_{thJA}			70	$^{\circ}\text{C}/\text{W}$
	TO-220C				60	
	TO-263-2				60	
	TO-247				60	

Electrical Characteristics

$T_J = 25^\circ\text{C}$, unless otherwise specified.

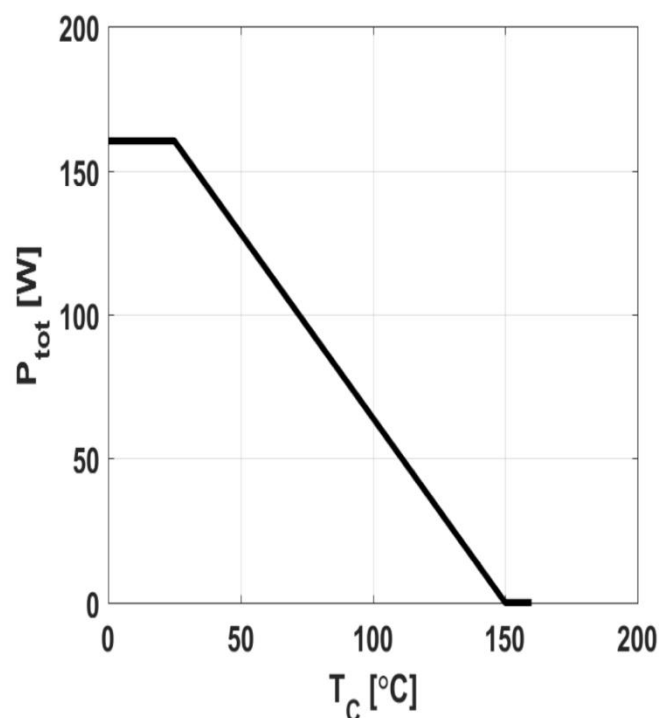
Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
Statistic Characteristics							
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D =250uA	650			V
Zero Gate Voltage Drain Current		I _{DSS}	V _{DS} =650V, V _{GS} =0V			10	uA
Gate-Body Leakage Current	Forward	I _{GSSF}	V _{GS} =20V, V _{DS} =0V			100	nA
	Reverse	I _{GSSR}	V _{GS} =-20V, V _{DS} =0V			-100	
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} =V _{GS} , I _D =0.25mA	3.0	4.0	5.0	V
Static Drain-Source On-Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =11A		147	170	mΩ
Gate Resistance		R _G	f=1MHz, Open Drain		0.9		Ω
Dynamic Characteristics							
Input Capacitance		C _{ISS}	V _{DS} =50V, V _{GS} =0V, f=1MHz		1.7		nF
Output Capacitance		C _{OSS}			130		pF
Reverse Transfer Capacitance		C _{RSS}			10.1		pF
Effective output capacitance, energy related ^{NOTE5}		C _{O(er)}	V _{GS} =0V, V _{DS} =0...400V		43.7		pF
Effective output capacitance, time related ^{NOTE6}		C _{O(tr)}			266		
Turn-on Delay Time		t _{d(on)}	V _{DD} =400V, I _D =11A R _G =5.3Ω, V _{GS} =10V		21		ns
Rise Time		t _r			8		
Turn-off Delay Time		t _{d(off)}			30		
Fall Time		t _f			7		
Gate Charge Characteristics							
Gate to Source Charge		Q _{gs}	V _{DD} =400V, I _D =11A V _{GS} =0 to 10V		11.5		nC
Gate to Drain Charge		Q _{gd}			12.1		
Gate Charge Total		Q _g			47.8		
Gate Plateau Voltage		V _{plateau}			6.5		V
Reverse Diode Characteristics							
Drain-Source Diode Forward Voltage		V _{SD}	V _{GS} =0V, I _{SD} =11A		0.9	1.1	V
Reverse Recovery Time		t _{rr}	V _R =400V, I _F =11A dI _F /dt=130A/us		130		ns
Reverse Recovery Charge		Q _{rr}			0.87		uC
Peak Reverse Recovery Current		I _{rrm}			12		A

Note:

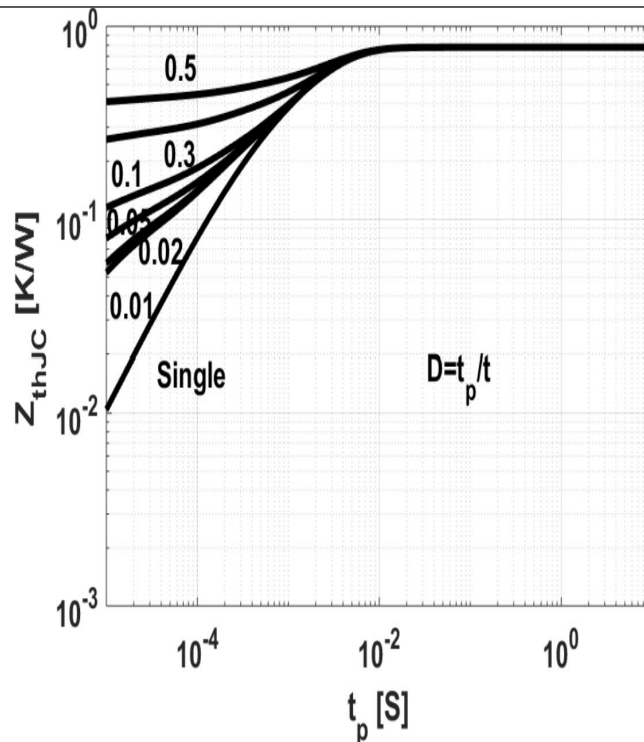
5. $C_{O(er)}$ is a fixed capacitance that gives the same stored energy as C_{OSS} while V_{DS} is rising from 0 to 480V

6. $C_{O(tr)}$ is a fixed capacitance that gives the same charging time as C_{OSS} while V_{DS} is rising from 0 to 480 V

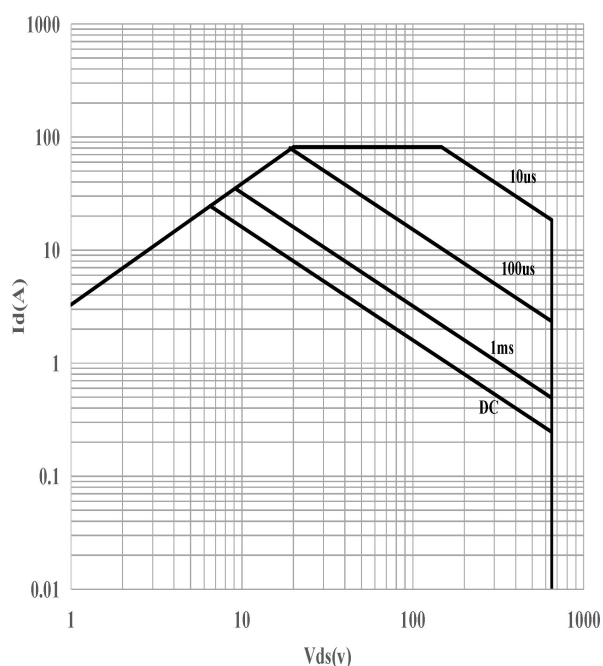
Typical Performance Characteristics

Figure 3: Power Dissipation


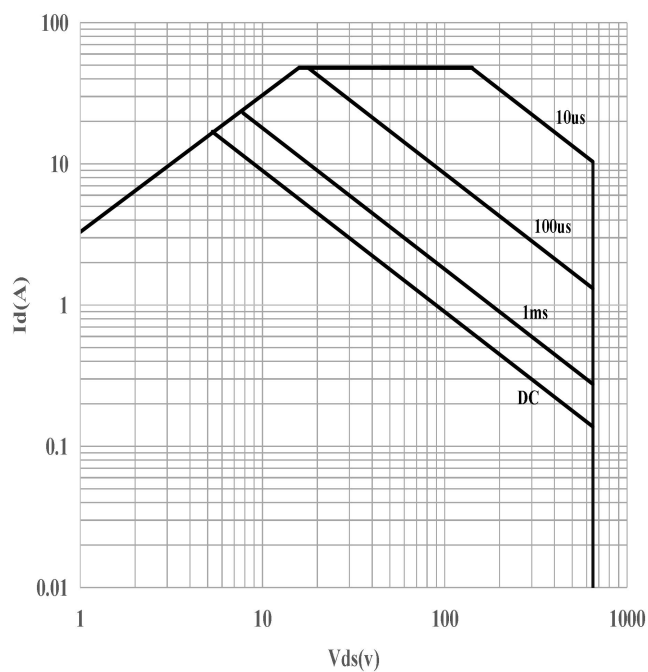
$$P_{tot} = f(T_c)$$

Figure 4: Max. Transient Thermal Impedance


$$Z_{thJC} = f(t_p); \text{ parameter: } D = t_p / T$$

Figure 5: Safe Operating Area


$$I_D = f(V_{DS}); T_c = 25^\circ\text{C}; V_{GS} > 7\text{V}; \text{ parameter } t_p$$

Figure 6: Safe Operating Area


$$I_D = f(V_{DS}); T_c = 80^\circ\text{C}; V_{GS} > 7\text{V}; \text{ parameter } t_p$$

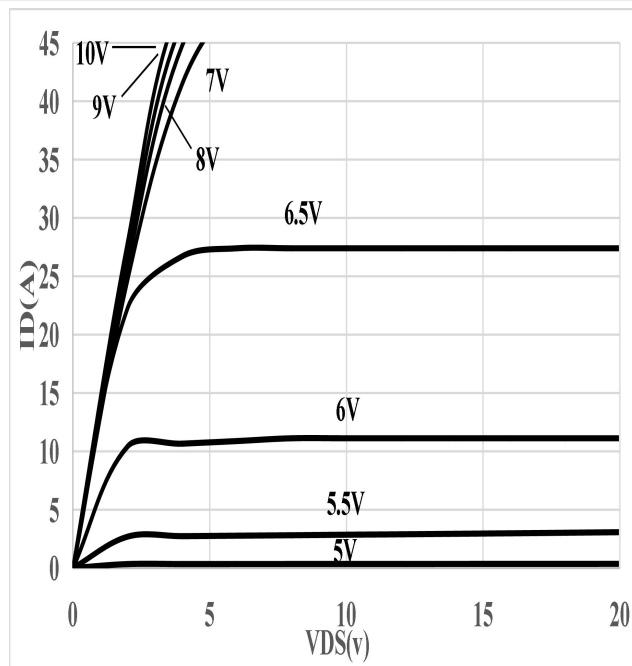
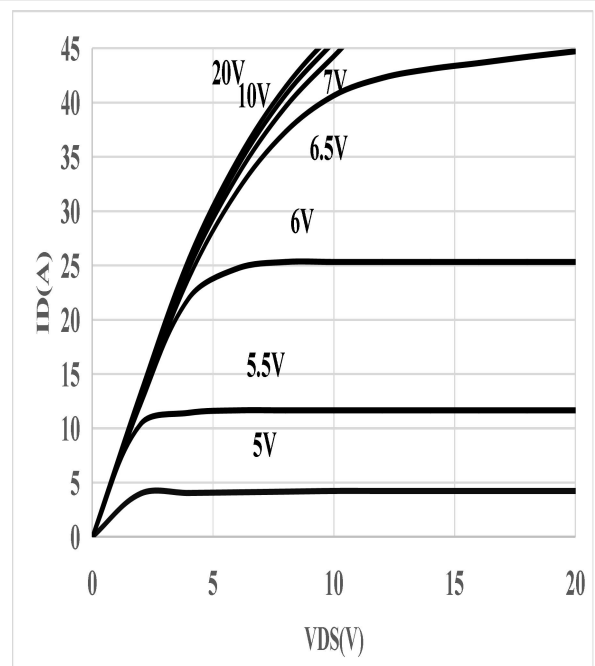
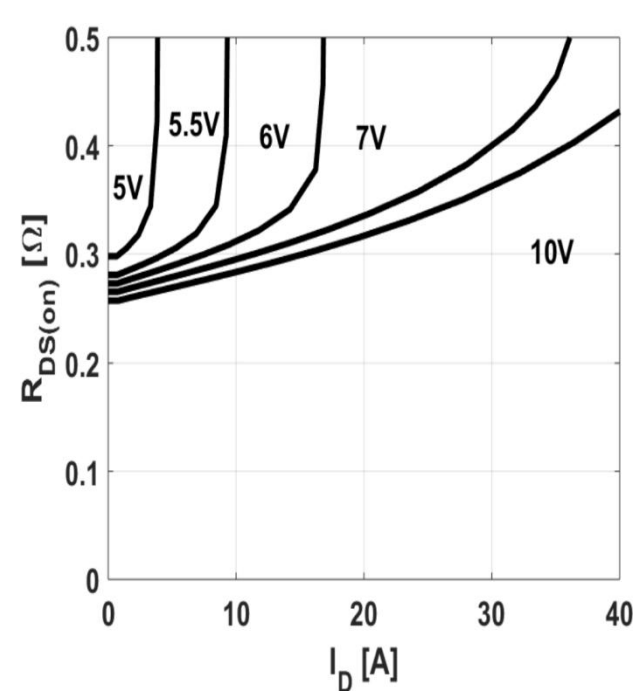
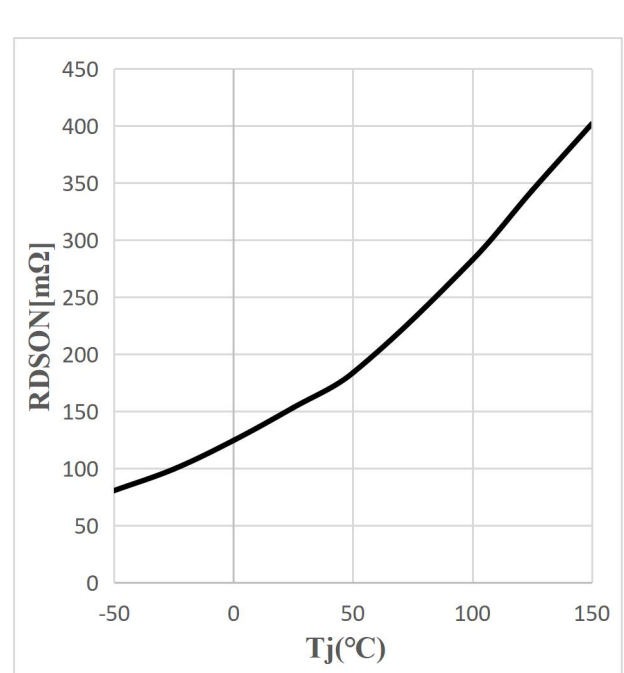
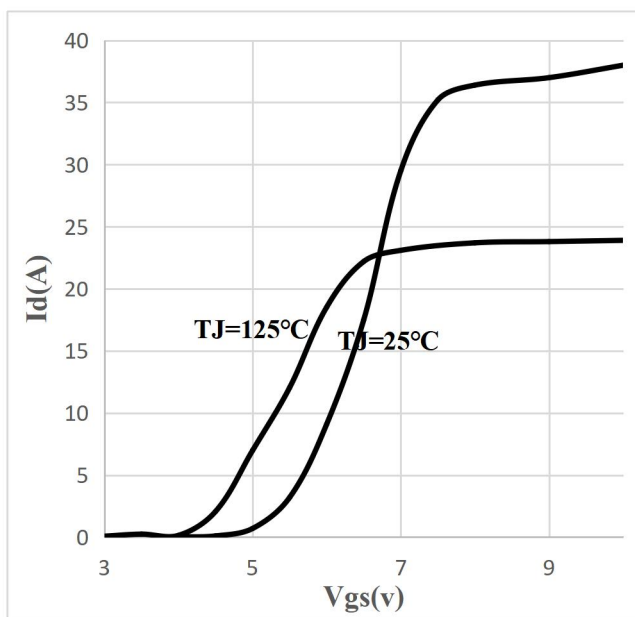
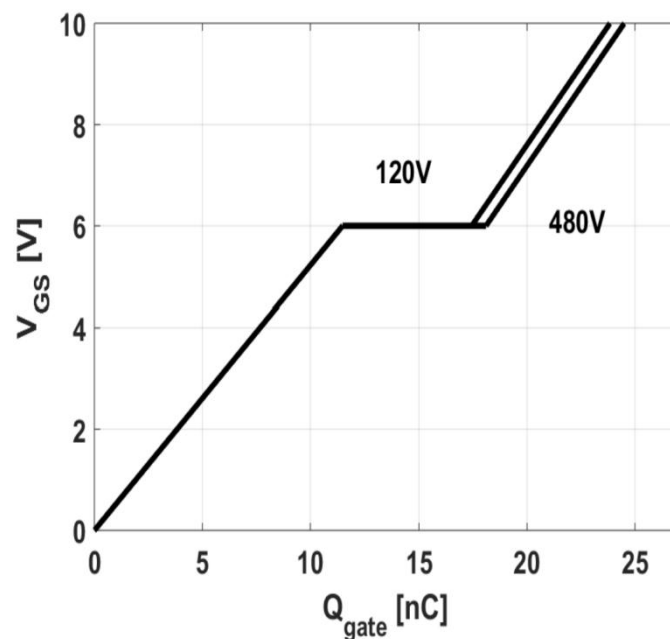
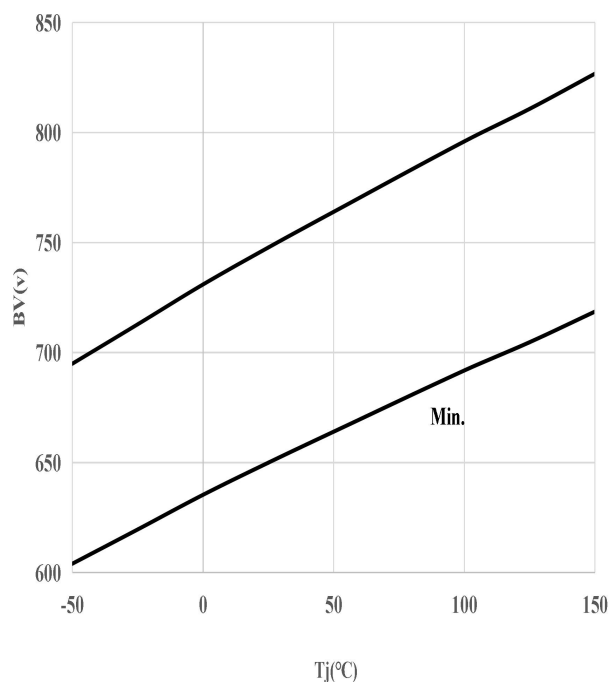
Figure 7: Typ. Output Characteristics

 $I_D = f(V_{DS}); T_j = 25^\circ\text{C}; \text{parameter: } V_{GS}$
Figure 8: Typ. Output Characteristics

 $I_D = f(V_{DS}); T_j = 125^\circ\text{C}; \text{parameter: } V_{GS}$
Figure 9: Typ. Drain-Source On-State Resistance

 $R_{DS(ON)} = f(I_D); T_j = 125^\circ\text{C}; \text{parameter: } V_{GS}$
Figure 10: Typ. Drain-Source On-State Resistance

 $R_{DS(ON)} = f(T_j); I_D = 11\text{A}; V_{GS} = 10\text{V}$

Figure 11: Typ. Transfer Characteristics


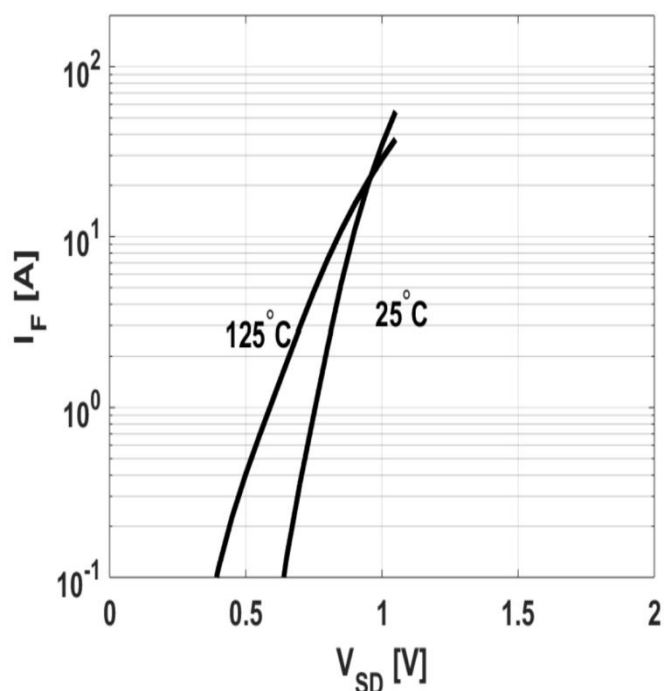
$$I_D = f(V_{GS}); V_{DS} = 20V$$

Figure 12: Typ. Gate Charge


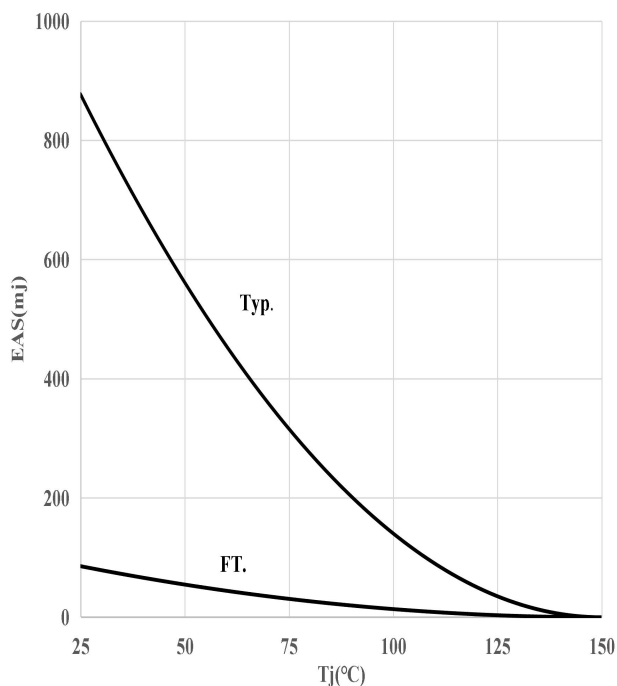
$$V_{GS} = f(Q_{gate}), I_D = 11A \text{ pulsed}$$

Figure 13: Drain-Source Breakdown Voltage


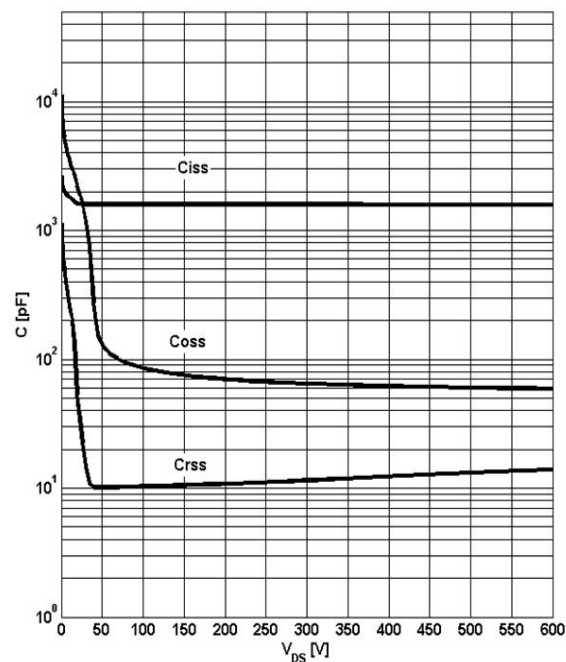
$$V_{BR(DSS)} = f(T_j); I_D = 10mA$$

Figure 14: Forward Characteristics of Reverse Diode


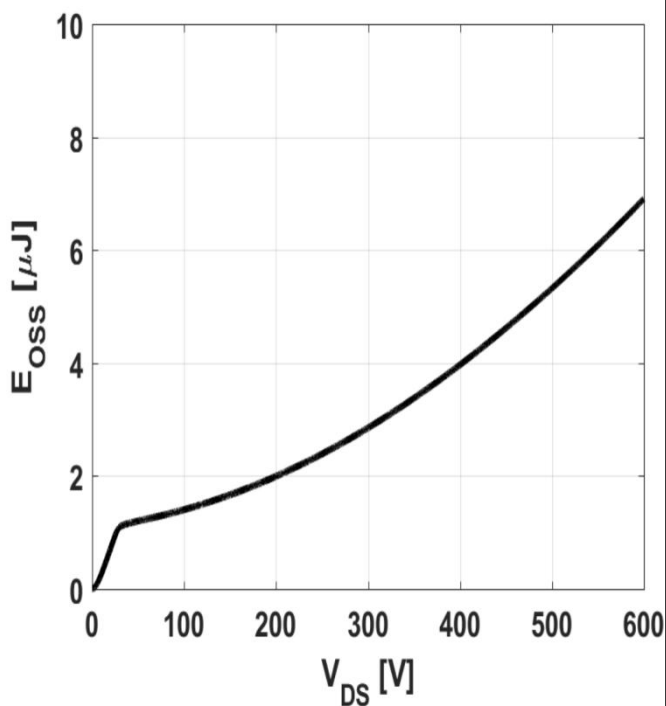
$$I_F = f(V_{SD}); \text{parameter: } T_j$$

Figure 15: Avalanche Energy


$$E_{AS}=f(T_j); V_{DD}=60V$$

Figure 16: Typ. Capacitances


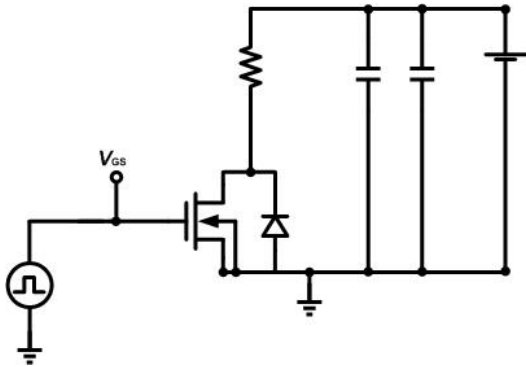
$$C=f(V_{DS}); V_{GS}=0; f=1MHz$$

Figure 17: Coss Stored Energy


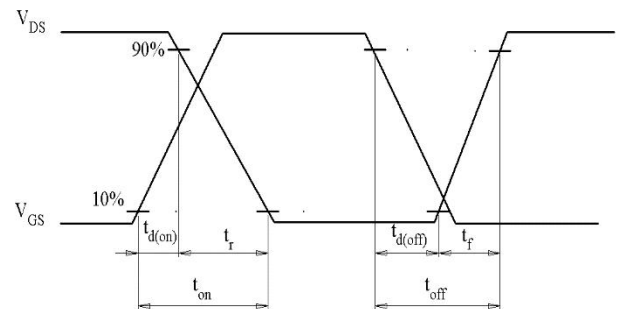
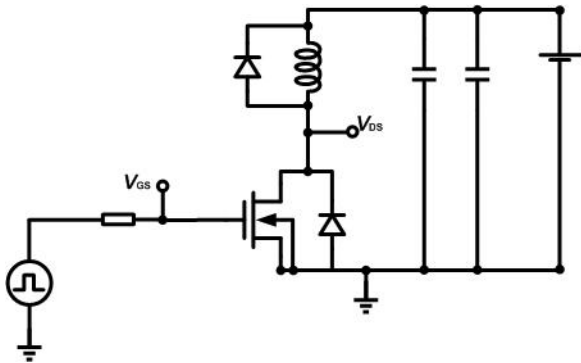
$$E_{oss}=f(V_{DS})$$

Test Circuits

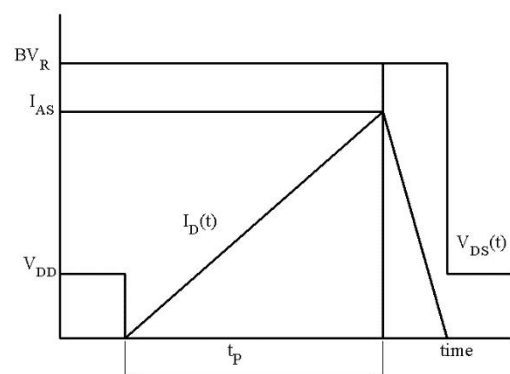
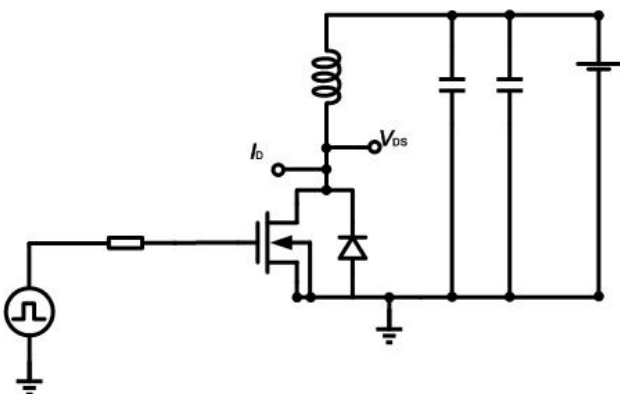
1. Gate Charge Test Circuit & Waveform



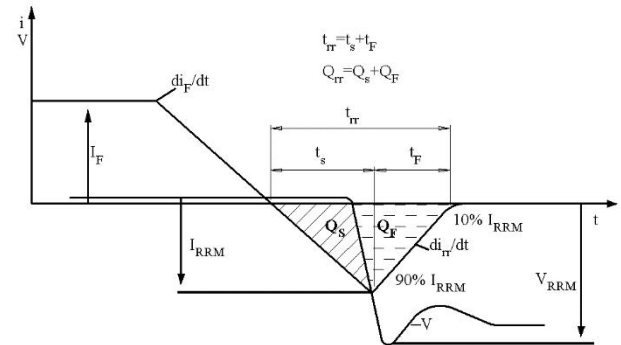
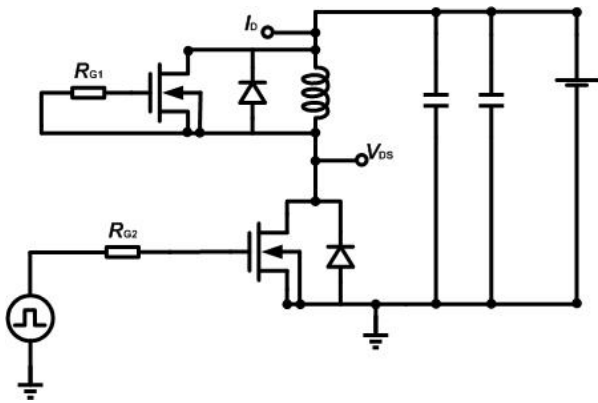
2. Switch Time Test Circuit

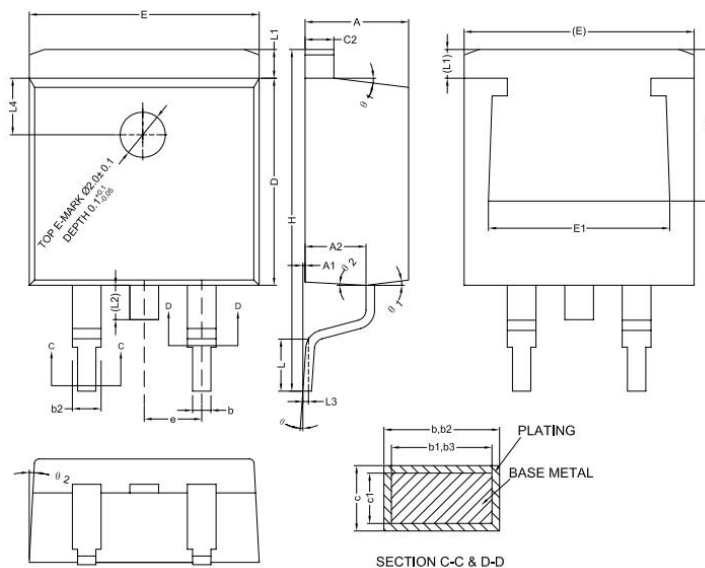


3. Unclaimed Inductive Switching Test Circuit & Waveforms



4. Test Circuit and Waveform for Diode Characteristics

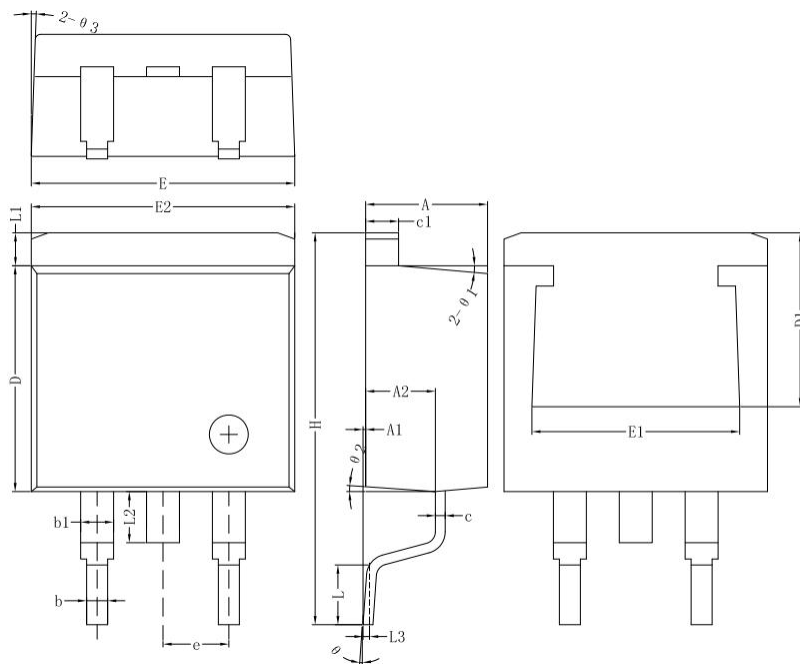


Mechanical Dimensions
TO-263-2 (Package 1)
Unit: mm


Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.40	4.57	4.70
A1	0.00	0.10	0.25
A2	2.59	2.69	2.79
b	0.77	-	0.90
b1	0.76	0.81	0.86
b2	1.23	-	1.36
b3	1.22	1.27	1.32
c	0.34	-	0.47
c1	0.33	0.38	0.43
c2	1.22	-	1.32
D	9.05	9.15	9.25
D1	6.60	-	-
E	10.06	10.16	10.26
E1	7.80	-	8.20
e	2.54(BSC)		
H	14.70	15.10	15.50
L	2.00	2.30	2.60
L1	1.17	1.27	1.40
L2	-	-	1.75
L3	0.25BSC		
L4	2.00REF		
θ	0°	-	8°
θ1	5°	7°	9°
θ2	1°	3°	5°

Mechanical Dimensions
TO-263-2 (Package 2)

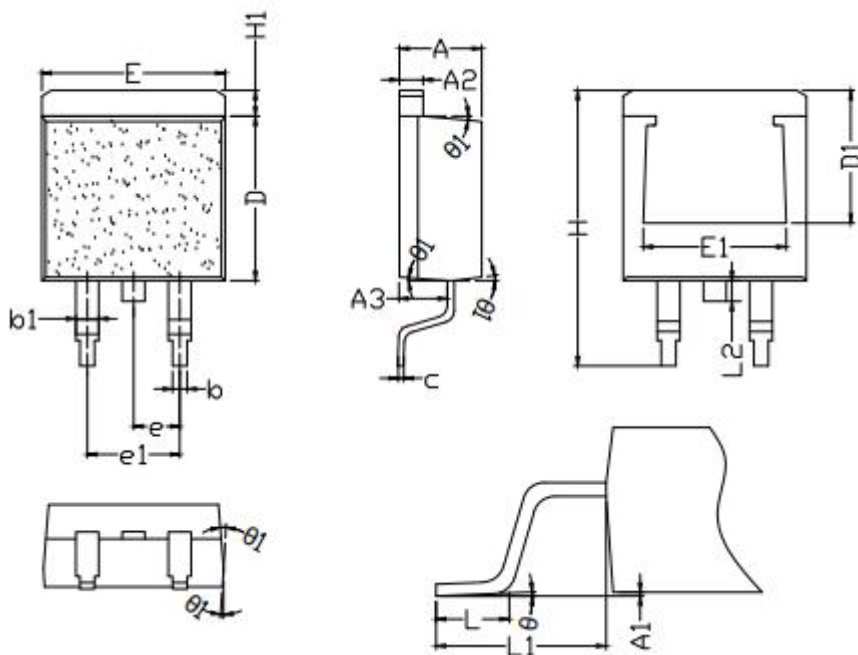
Unit: mm



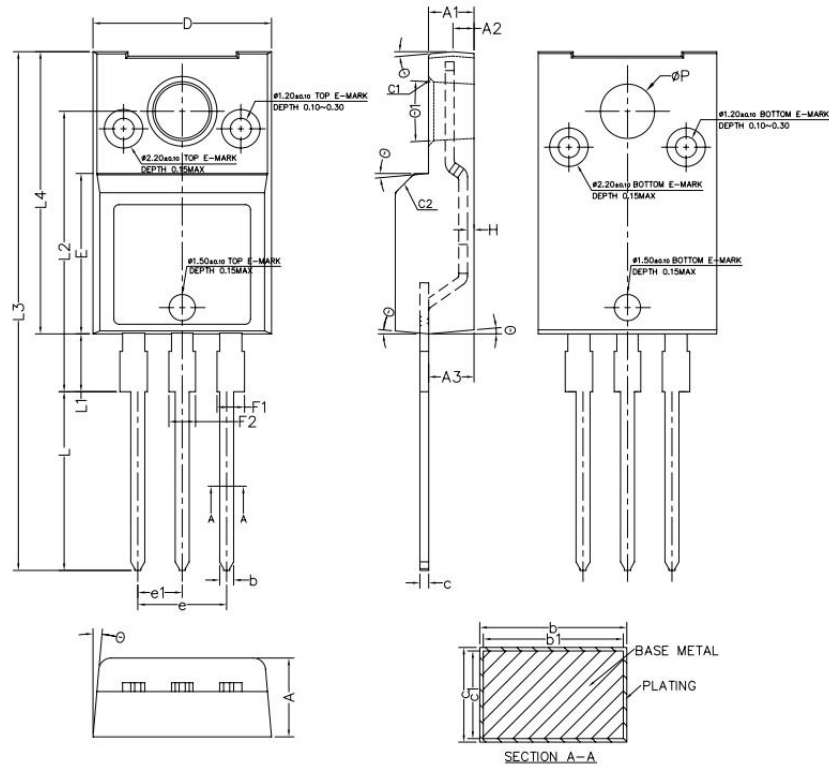
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.55	4.70	4.85
A1	0.00	0.10	0.25
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1	-	1.27	-
c	0.36	0.38	0.61
c1	1.17	1.27	1.37
D	8.55	8.70	8.85
D1	-	7.2	-
E	10.01	10.16	10.31
E1	-	7.80	-
E2	9.98	10.08	10.18
e	-	2.54	-
H	14.70	15.10	15.50
L	2.00	2.30	2.70
L1	1.17	1.27	1.40
L2	-	-	2.20
L3	-	0.25BSC	-
θ	0°	-	8°
θ1		5°	
θ2		4°	
θ3		4°	

Mechanical Dimensions
TO-263-2 (Package 3)

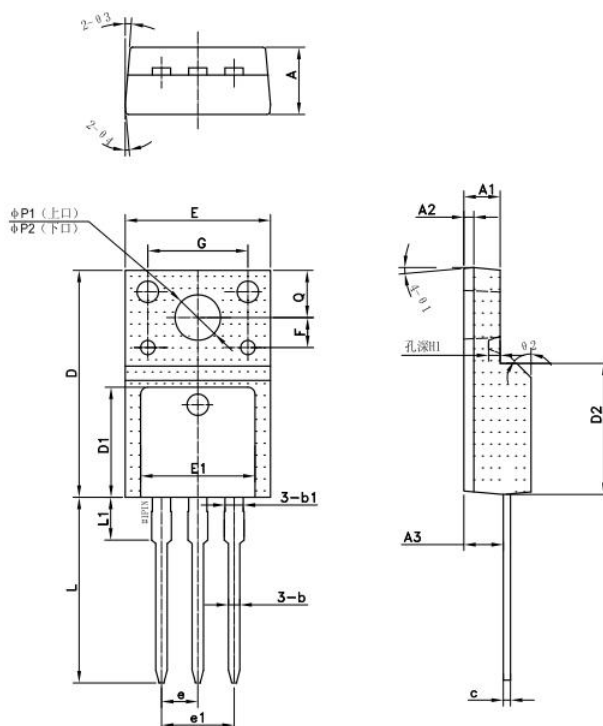
Unit: mm



Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.42	4.52	4.62
A1	0.00	0.10	0.25
A2	1.24	1.27	1.32
A3	2.50	2.60	2.70
b	0.77	0.81	0.84
b1	1.23	1.28	1.41
c	0.33	0.38	0.43
D	8.80	8.95	9.10
D1	7.2REF		
E	9.92	10.07	10.22
E1	7.85REF		
e	2.50	2.54	2.58
e1	5.08REF		
H	14.80	15.10	15.30
H1	1.12	1.28	1.42
L	2.10	2.23	2.36
L1	4.55	4.75	4.95
L2	1.10	1.30	1.50
θ	0°	2°	5°
θ1	3°	-	5°

Mechanical Dimensions
TO-220F (Package 1)
Unit: mm


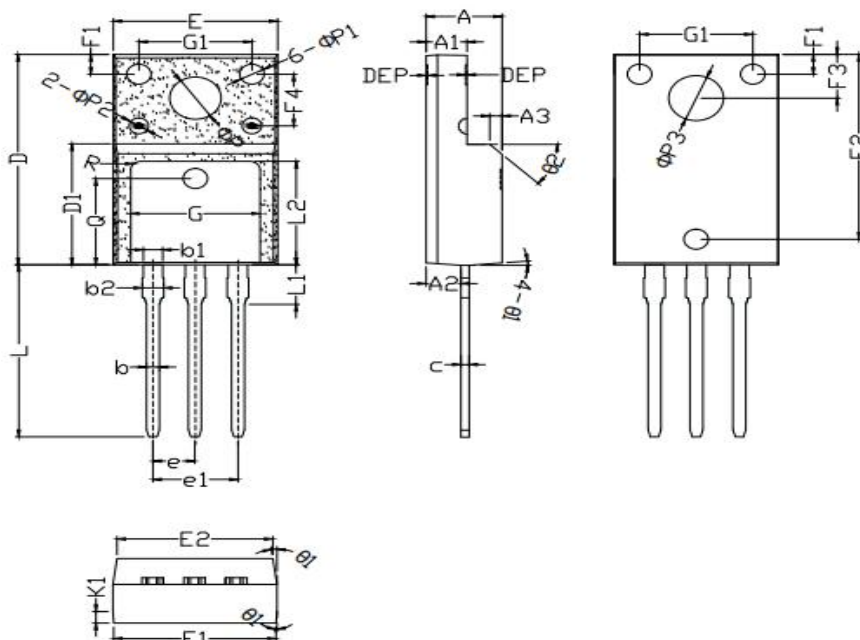
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.40	4.50	4.60
A1	2.50	2.60	2.70
A2	1.10	1.20	1.30
A3	2.49	2.59	2.69
b	0.76	-	0.89
b1	0.75	0.80	0.85
c	0.46	-	0.59
c1	0.45	0.50	0.55
C1	0.20	0.30	0.40
C2	1.00	1.10	1.20
D	10.10	10.20	10.30
E	9.05	9.15	9.25
e	4.98	5.08	5.18
e1	2.44	2.54	2.64
F1	1.22	-	1.60
F2	1.17	-	1.55
H	0.32	0.37	0.42
L	10.00	10.20	10.40
L1	3.15	3.30	3.45
L2	15.85	16.00	16.15
L3	29.30	29.60	29.90
L4	16.00	16.10	16.20
P	3.00	3.10	3.20
θ	3°	5°	7°
θ1	4°	6°	8°

Mechanical Dimensions
TO-220F (Package 2)
Unit: mm


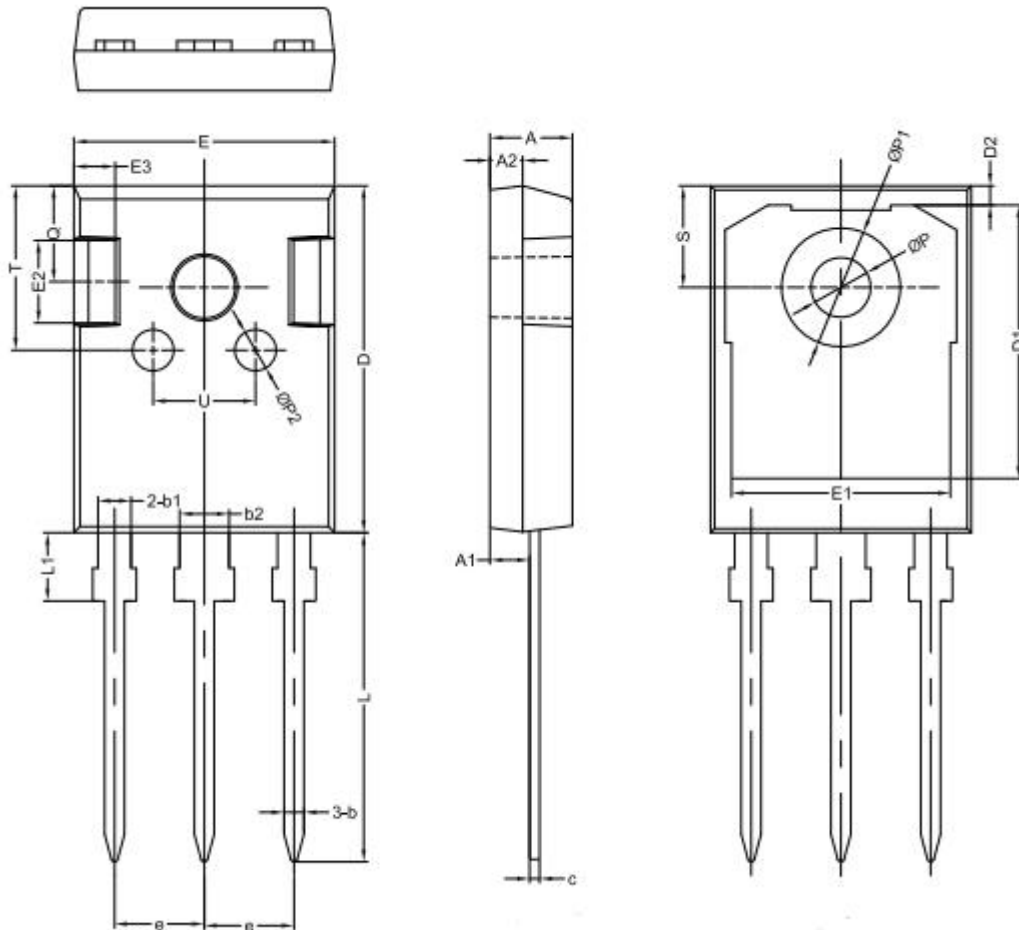
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.50	4.70	4.90
A1	2.34	2.54	2.70
A2	-	0.70	-
A3	2.56	2.76	2.96
b	0.70	0.80	0.95
b1	-	1.28	-
c	0.45	0.50	0.65
D	15.67	15.87	16.07
D1	-	7.70	-
D2	-	9.12	-
E	9.96	10.16	10.36
E1	-	8.00	-
e	2.54		
e1		5.08	
F		2.1	
G		7	
H1	-	0.81	-
L	12.48	12.98	13.20
L1	-	2.93	-
ΦP1 (上口)	2.98	3.18	3.38
ΦP2 (下口)	3.20	3.40	3.60
Q	3.10	3.30	3.50
θ1		5°	
θ2		45°	
θ2		5°	
θ3		5°	

Mechanical Dimensions
TO-220F (Package 3)

Unit: mm



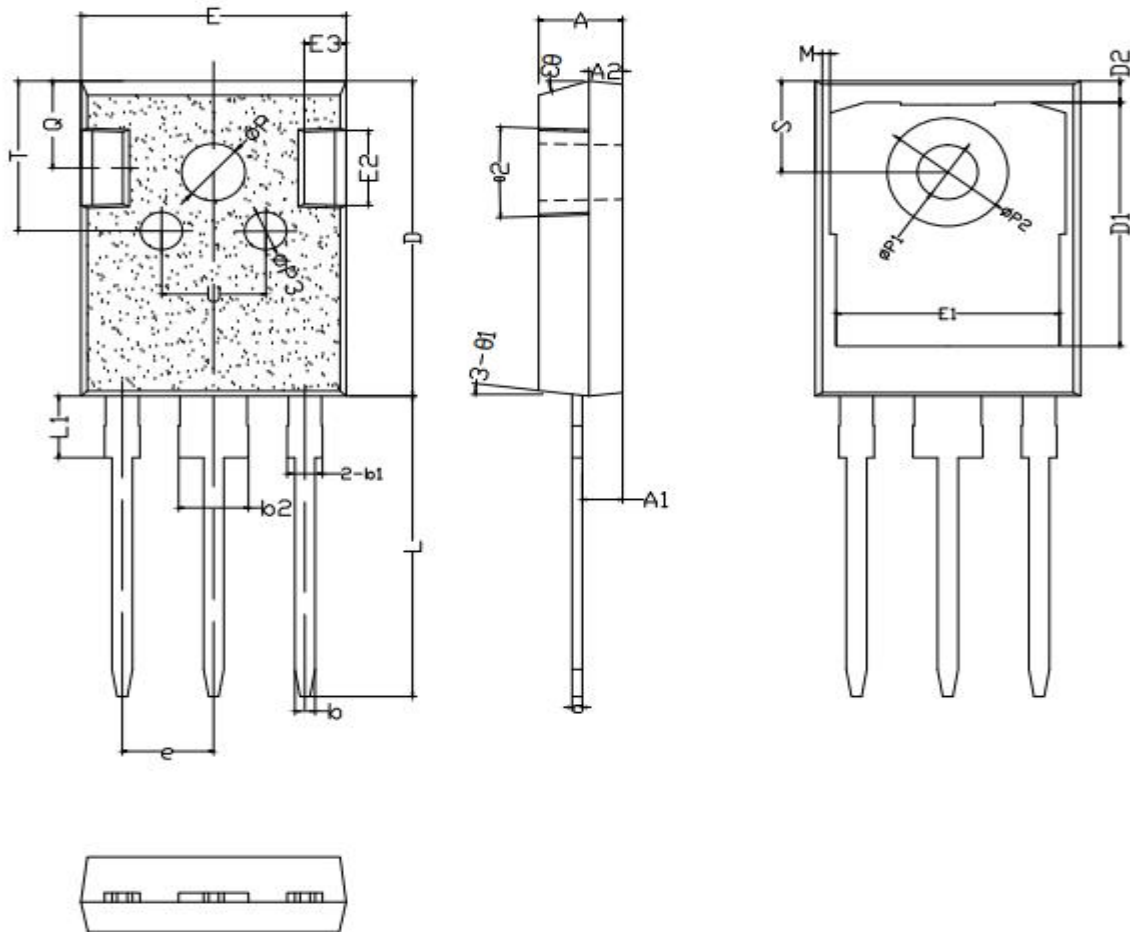
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.50	4.70	4.90
A1	2.34	2.54	2.74
A2	2.60	2.80	2.95
A3	1.0REF		
b	0.75	0.80	0.85
b1	1.18	1.20	1.24
b2	1.18	1.24	1.30
c	0.45	0.50	0.55
D	15.67	15.87	16.07
D1	9.04	9.12	9.20
E	10.00	10.16	10.30
E1	9.94	10.06	10.30
E2	9.40	9.50	9.60
e	2.50	2.54	2.58
e1	5.08REF		
L	12.78	12.98	13.18
L1	2.70	2.92	3.20
L2	7.70	7.80	7.90
Q	6.50REF		
ΦP	3.08	3.18	3.28
ΦP1	1.45	1.55	1.65
ΦP2	0.95	1.15	1.35
ΦP3	3.30	3.40	3.50
θ1	3°	5°	7°
θ2	42°	45°	48°
F1	1.40	1.50	1.60
F2	13.80	13.90	14.00
F3	3.20	3.30	3.40
F4	3.70	3.90	4.10
G	7.80	8.00	8.20
G1	6.90	7.00	7.10
K1	0.65	0.70	0.75

Mechanical Dimensions
TO-247(Package 1)
Unit: mm


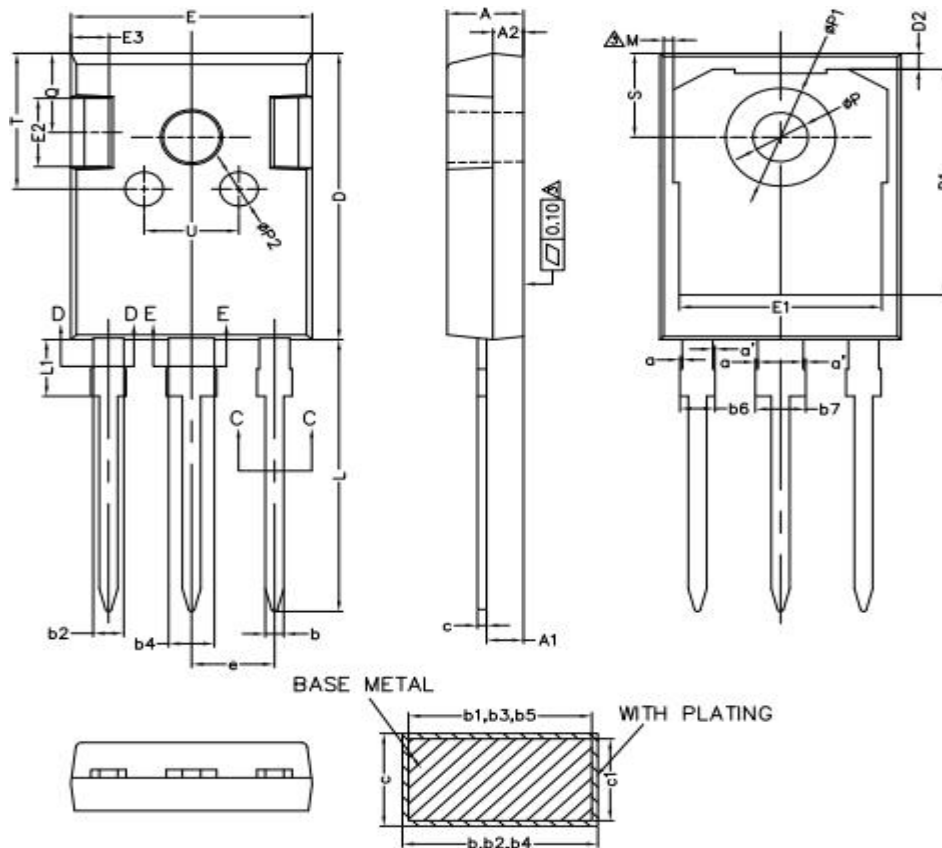
Symbol	Dimensions(mm)			Symbol	Dimensions(mm)		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.80	5.00	5.20	E1	-	13.30	-
A1	2.21	2.41	2.61	E2	-	5.00	-
A2	1.90	2.00	2.10	E3	-	2.50	-
b	1.10	1.20	1.35	L	19.42	19.92	20.42
b1	-	2.00	-	L1	-	4.13	-
b2	-	3.00	-	P	3.50	3.60	3.70
c	0.55	0.60	0.75	P1	-	7.19	-
D	20.80	21.00	21.20	P2	-	2.50	-
D1	-	16.55	-	Q	-	5.80	-
D2	-	1.20	-	S	6.05	6.15	6.25
E	15.60	15.80	16.0	T	-	10.00	-
U	-	6.20	-				

Mechanical Dimensions
TO-247(Package 2)

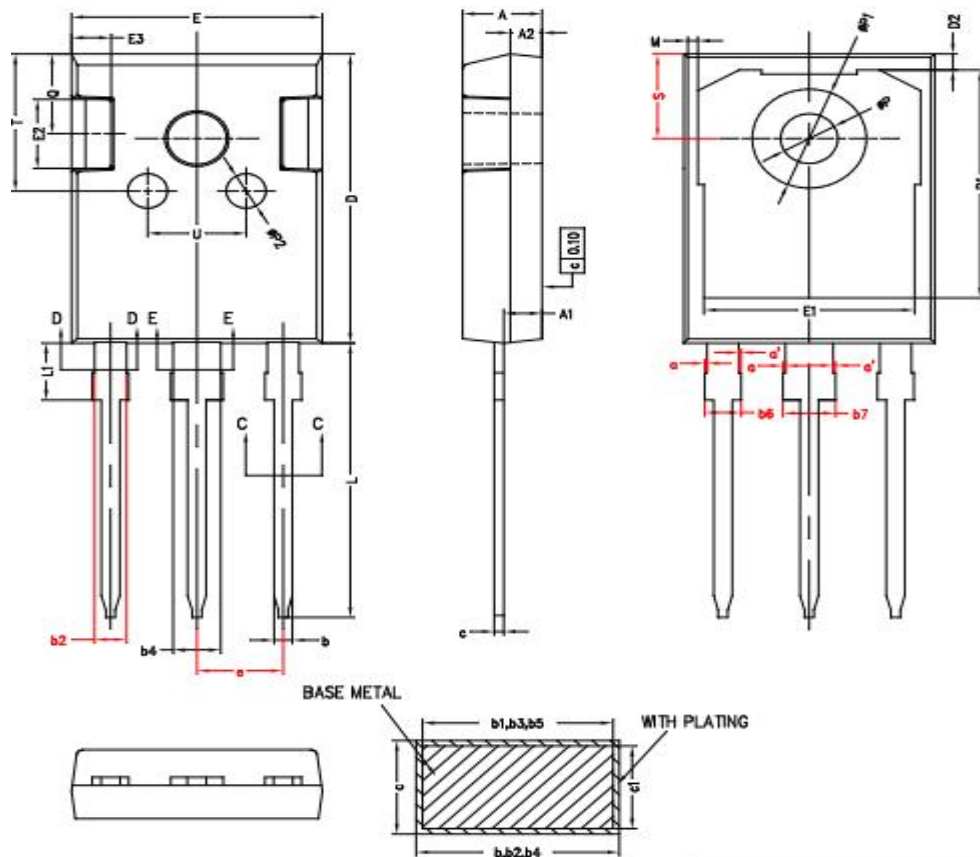
Unit: mm



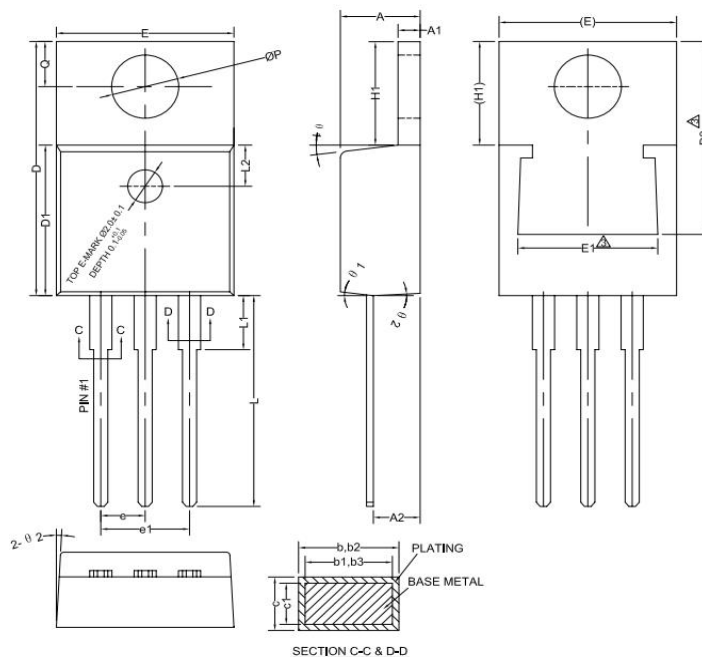
Symbol	Dimensions(mm)			Symbol	Dimensions(mm)		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.90	5.00	5.10	E1	13.10	13.25	13.40
A1	2.31	2.41	2.51	E2	4.85	4.95	5.10
A2	1.90	2.00	2.10	E3	2.40	2.50	2.60
b	1.15	1.20	1.25	L	19.80	19.98	20.15
b1	1.95	2.10	2.25	L1	-	-	4.30
b2	2.95	3.10	3.25	ΦP	3.60	3.70	3.80
c	0.55	0.60	0.65	ΦP1	3.40	3.50	3.60
D	20.90	21.00	21.10	ΦP2	6.90	7.10	7.30
D1	16.35	16.55	16.75	Q	5.60	5.80	6.00
D2	1.05	1.20	1.35	S	6.05	6.15	6.25
E	15.70	15.80	15.90	T	9.80	10.00	10.20
U	6.00	6.20	6.40	e	5.40	5.44	5.48
Ø1	5°	7°	9°	ΦP3	2.40	2.50	2.60
Ø2	1°	3°	5°	Ø3	13°	15°	17°

Mechanical Dimensions
TO-247(Package 3)
Unit: mm


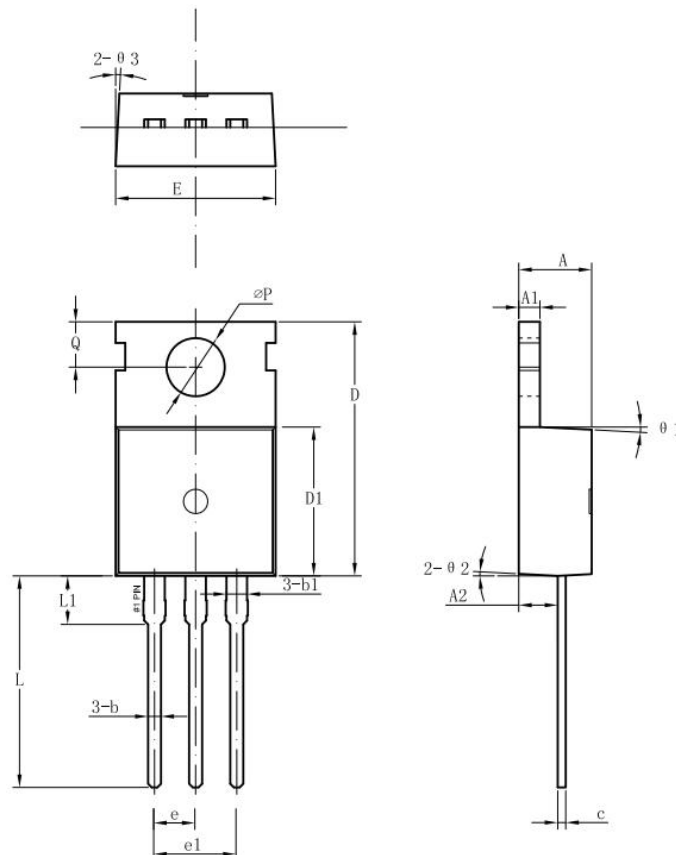
Symbol	Dimensions(mm)			Symbol	Dimensions(mm)		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.90	5.00	5.10	c1	0.58	0.60	0.62
A1	2.31	2.41	2.51	D	20.90	21.00	21.10
A2	1.90	2.00	2.10	D1	16.25	16.55	16.85
b	1.16	-	1.26	D2	1.05	1.20	1.35
b1	1.15	1.20	1.22	E	15.70	15.80	15.90
b2	1.96	-	2.06	E1	13.10	13.30	13.50
b3	1.95	2.00	2.02	E2	4.90	5.00	5.10
b4	2.96	-	3.06	E3	2.40	2.50	2.60
b5	2.95	3.00	3.02	e	5.34	5.44	5.54
b6	-	-	2.25	L	19.80	19.92	20.10
b7	-	-	3.25	L1	3.95	4.13	4.30
c	0.59	-	0.66	M	0.35	-	0.95
P	3.50	3.60	3.70	P1	7.00	-	7.40
P2	2.40	2.50	2.60	Q	5.60	-	6.00
S	6.05	6.15	6.25	T	9.80	-	10.20
U	6.00	-	6.40	a	0	-	0.15
a'	0	-	0.15				

Mechanical Dimensions
TO-247(Package 4)
Unit: mm


Symbol	Dimensions(mm)			Symbol	Dimensions(mm)		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.90	5.00	5.10	E2	4.90	5.00	5.10
A1	2.31	2.41	2.51	E3	2.40	2.50	2.60
A2	1.90	2.00	2.10	e	5.34	5.44	5.54
b	1.12	-	1.22	L	19.80	19.92	20.10
b1	1.11	1.16	1.18	L1	3.95	4.13	4.30
b2	1.96	-	2.06	P	3.50	3.60	3.70
c	0.59	-	0.66	P1	7.00	-	7.40
D	20.90	21.00	21.10	P2	2.40	2.50	2.60
D1	16.25	16.55	16.85	Q	5.60	-	6.00
D2	1.05	1.20	1.35	S	6.05	6.15	6.25
E	15.70	15.80	15.90	T	9.80	-	10.20
E1	13.10	13.30	13.50	U	6.00	-	6.40
b3	1.95	2.00	2.02	b6	-	-	2.25
b4	2.96	-	3.06	b7	-	-	3.25
b5	2.95	3.00	3.02	c1	0.58	0.60	0.62
M	0.35	-	0.95	a	0	-	0.15
a'	0	-	0.15				

Mechanical Dimensions
TO-220C (Package 1)
Unit: mm


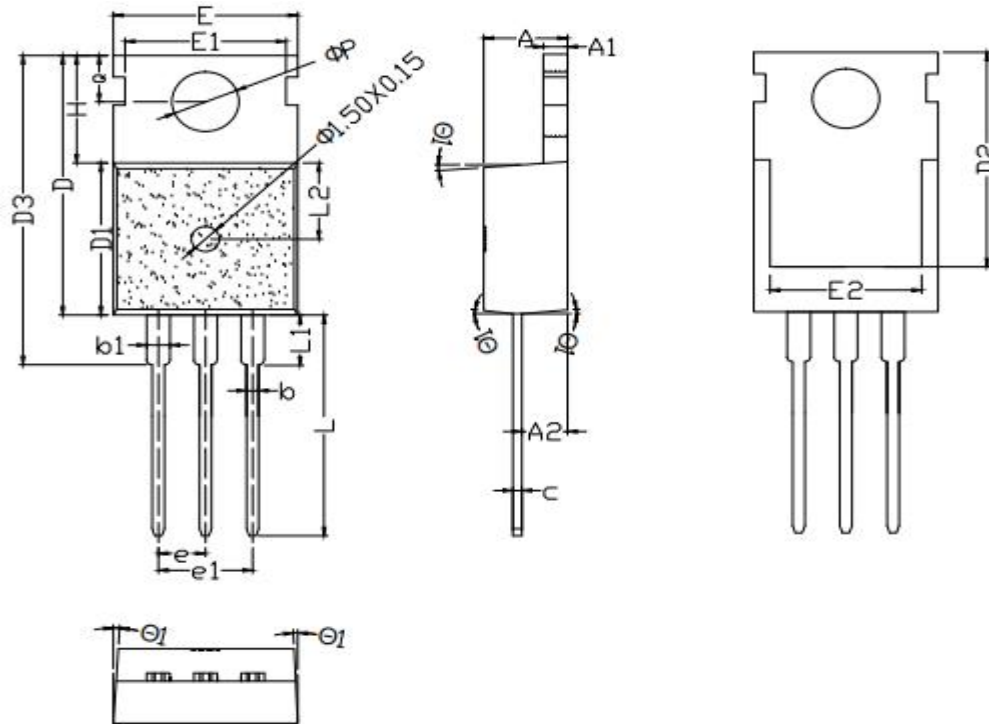
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.40	4.57	4.70
A1	1.22	-	1.32
A2	2.59	2.69	2.79
b	0.77	-	0.90
b1	0.76	0.81	0.86
b2	1.23	-	1.36
b3	1.22	1.27	1.32
c	0.34	-	0.47
c1	0.33	0.38	0.43
D	15.15	15.45	15.75
D1	9.05	9.15	9.25
D2	11.40	-	12.88
E	9.96	10.16	10.36
E1	6.86	-	8.89
e	2.44	2.54	2.64
e1	4.98	5.08	5.18
H1	6.10	6.30	6.50
L	12.70	-	13.12
L1	-	-	3.90
ΦP	3.80	3.84	3.88
Q	2.60	-	2.90
θ1	5°	7°	9°
θ2	1°	2°	5°

Mechanical Dimensions
TO-220C (Package 2)
Unit: mm


Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.30	4.50	4.70
A1	1.25	1.30	1.40
A2	2.20	2.40	2.60
b	0.70	0.80	0.95
b1	-	1.27	-
c	0.40	0.50	0.65
D	15.20	15.70	16.20
D1	9.00	9.20	9.40
E	9.70	10.00	10.20
e		2.54	
e1		5.08	
L	12.60	13.08	13.60
L1	-	3.00	-
ϕP	3.50	3.60	3.80
Q	2.60	2.80	3.00
$\theta 1$		3°	
$\theta 2$		3°	
$\theta 2$		3°	

Mechanical Dimensions
TO-220C (Package 3)

Unit: mm



Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.40	4.50	4.60
A1	1.25	1.30	1.35
A2	2.30	2.40	2.50
b	0.70	0.80	0.90
b1	1.25	1.33	1.42
c	0.45	0.50	0.55
D	15.50	15.75	16.00
D1	9.10	9.20	9.30
D2	12.90	13.10	13.30
D3	15.45	15.80	16.15
E	9.80	10.02	10.15
e	2.54BSC		
e1	5.08BSC		
L	13.00	13.28	13.45
L1	-	-	3.40
ΦP	3.55	3.65	3.75
Q	2.65	2.75	2.85
θ1	2°	-	7°
E1	8.55	8.70	8.85
E2	7.40	7.60	7.80
H	6.40	6.50	6.60
L2	4.50	4.65	4.80



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